

# RT3C88M

For high voltage switch  
Silicon NPN epitaxial type dual transistor

## DESCRIPTION

RT3C88M is Silicon NPN epitaxial type dual transistor. By using this transistor it is possible to reduce the size of the set, greatly reduce product and man-hours.

## FEATURE

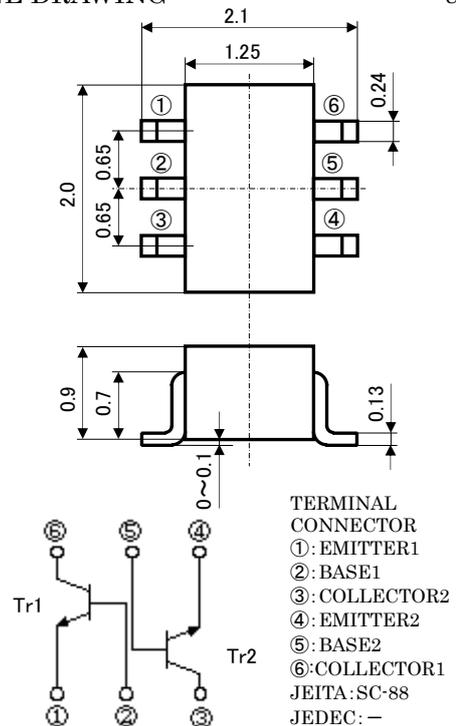
- High VCEO VCEO=160V
- High direct current amplification factor
- Collector saturation voltage is low  
VCE (sat) = 0.15 V (maximum)

## APPLICATION

For high voltage switch.

## OUTLINE DRAWING

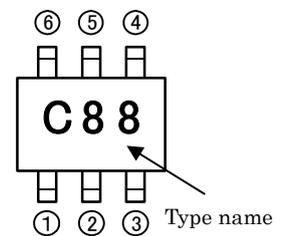
Unit: mm



## MAXIMUM RATING (Ta=25°C) (Tr1, Tr2.)

SYMBOL	PARAMETER	RATING	UNIT
VCBO	Collector to Base voltage	180	V
VEBO	Emitter to Base voltage	6	V
VCEO	Collector to Emitter voltage	160	V
ICM	Peak collector current	200	mA
IC	Collector current	100	mA
PT	Total dissipation	200	mW
Tj	Junction temperature	+150	°C
Tstg	Storage temperature	-55~+150	°C

## MARKING



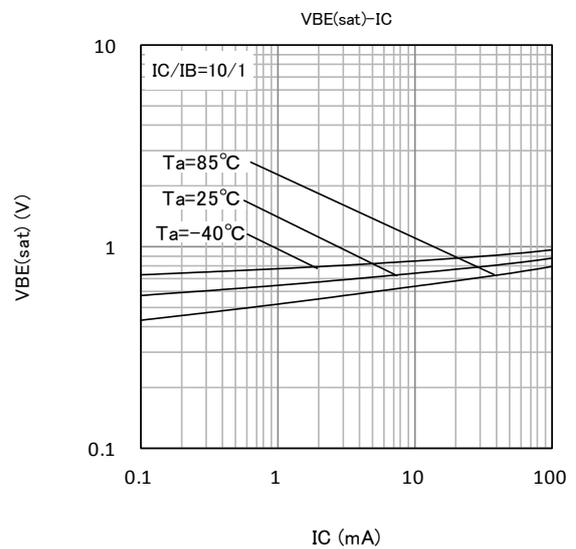
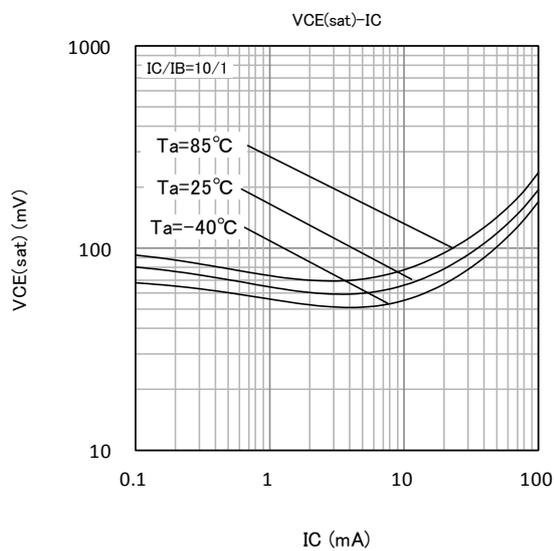
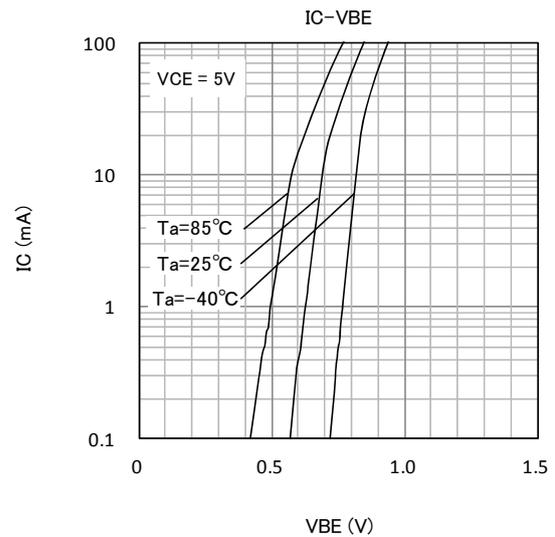
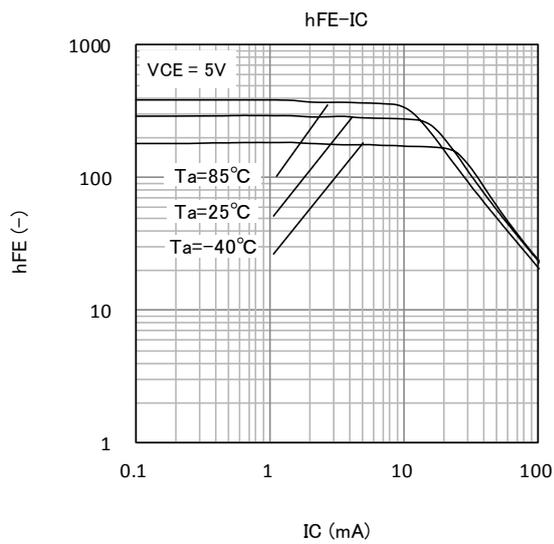
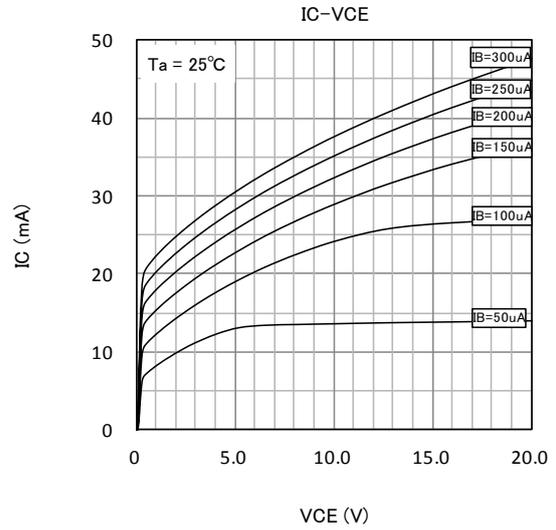
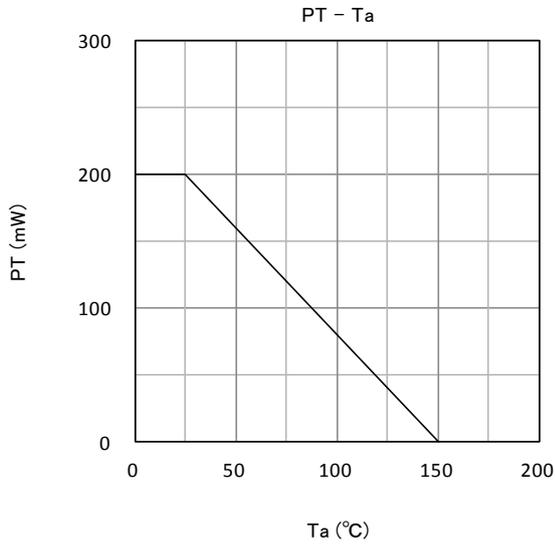
## ELECTRICAL CHARACTERISTICS (Ta=25°C) (Tr1, Tr2.)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
V(BR)CBO	C to B breakdown voltage	IC=100μA, IE=0A	180	-	-	V
V(BR)EBO	E to B breakdown voltage	IE=10μA, IC=0A	6	-	-	V
V(BR)CEO	C to E breakdown voltage	IC=1mA, RBE=∞	160	-	-	V
ICBO	Collector cut off current	VCB=120V, IE=0A	-	-	100	nA
IEBO	Emitter cut off current	VEB=4V, IC=0A	-	-	100	nA
hFE1	DC forward current gain1	VCE=5V, IC=1mA	150	-	-	-
hFE2	DC forward current gain2	VCE=5V, IC=10mA	200	-	500	-
hFE3	DC forward current gain3	VCE=5V, IC=50mA	27	-	-	-
VCE(sat)	C to E saturation voltage	IC=10mA, IB=1mA	-	-	0.15	V
VBE(sat)	B to E saturation voltage	IC=10mA, IB=1mA	-	-	1.0	V
fT	Gain bandwidth product	VCE=10V, IE=-10mA	100	-	300	MHz
Cob	Collector output capacitance	VCB=10V, IE=0A, f=1MHz	-	1.7	6	pF

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## Standard characteristics





**Keep safety first in your circuit designs!**

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